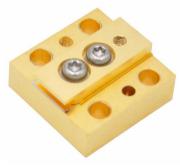


# **Diode Laser Packaged Bars and Arrays**

### 808nm Conduction-cooled Packaged Bars (QCW)

LDA series high power packaged bars provide OEM customers with scalable power up to kilowatts for pumping, industrial, medical and applications. The packaged laser bars can be configured for enhanced brightness through stacking, scaled linearly or vertically for optimized light and material integration. LDA series offer

- Wavelengths at 808nm to 1100nm range
- Modular and Compact design for ease of integration
- Up to 100W CW and 300W QCW laser diode bars for high brightness
- Packaged 10mm laser diode bar, various standard bar configurations (custom bar configurations available on request)



## Parameters (20℃)

| Conduction-cooled Packaged Bars |                                  |       |                 |       |       |
|---------------------------------|----------------------------------|-------|-----------------|-------|-------|
| Parameter                       |                                  | Unit  | LDAQ1-0808-***W |       |       |
| Optical<br>Parameter            | Operation Mode                   | -     | QCW             |       |       |
|                                 | Center Wavelength                | nm    | 808             |       |       |
|                                 | Output Power                     | W     | 100             | 200   | 300   |
|                                 | Spectral Width                   | nm    | < 5             | < 5   | < 5   |
|                                 | Wavelength&<br>Temperature Ratio | nm/°C | 0.28            | 0.28  | 0.28  |
|                                 | Fast Axis Divergence             | deg   | < 39            | < 39  | < 39  |
|                                 | Slow Axis Divergence             | deg   | < 10            | < 10  | < 10  |
|                                 | Pulse Width                      | μs    | <500            |       |       |
|                                 | Duty Ratio                       | %     | ≤ 4             |       |       |
| Electrical<br>Parameter         | Threshold Current                | А     | < 25            | <30   | < 30  |
|                                 | Operating Current                | А     | ≤ 110           | ≤ 200 | ≤ 300 |
|                                 | Operating Voltage                | V     | < 2.0           | < 2.0 | < 2.0 |
| Thermal<br>Parameter            | Operating Temperature            | °C    | 15~35           |       |       |
|                                 | Storage Temperature              | °C    | -10 ~ 60        |       |       |

#### Hi-Tech Optoelectronics Co., Ltd. TEL: +86(10) 6076 9899

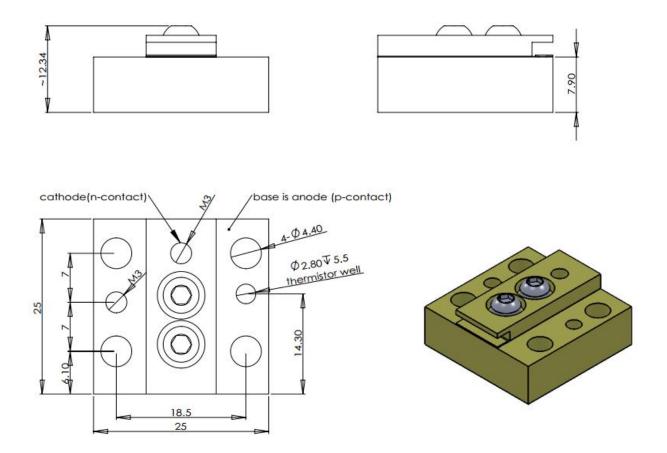
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### Package Information



### Notice

- 1. Item model notice: LDAQ1 (item model)-0808 (center wavelength)-\*\*\*\* (output power).
- 2. Package data is only for reference, which can be customized according to client's designed drawings.
- 3. Please make sure laser diode is operated under the temperature between  $15^{\circ}$ C and  $35^{\circ}$ C, as high temperature will increase threshold current, decrease exchange rate and accelerate the aging.
- 4. Please take measures to avoid condensation, which will cause aging of laser diode.
- 5. For more information, please contact Hi-Tech Optoelectronics Co., Ltd.

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